

SKiiP 342 GD 120 - 314 CTV

Absolute Maximum Ratings			
Symbol	Conditions ¹⁾	Values	Units
V_{isol} ⁴⁾	AC, 1min	3000	V
T_{op}, T_{stg}	Operating / stor. temperature	-25...+85	°C
IGBT and Inverse Diode			
V_{CES}		1200	V
V_{CC} ⁵⁾	Operating DC link voltage	900	V
I_C	IGBT	300	A
T_j ³⁾	IGBT + Diode	-40...+150	°C
I_F	Diode	300	A
I_{FM}	Diode, $t_p < 1$ ms	600	A
I_{FSM}	Diode, $T_j = 150$ °C, 10ms; sin	2160	A
I^2_t (Diode)	Diode, $T_j = 150$ °C, 10ms	23	kAs ²
Driver			
V_{S1}	Stabilized Power Supply	18	V
V_{S2}	Non-stabilized Power Supply	30	V
f_{smax}	Switching frequency	20	kHz
dV/dt	Primary to secondary side	75	kV/μs

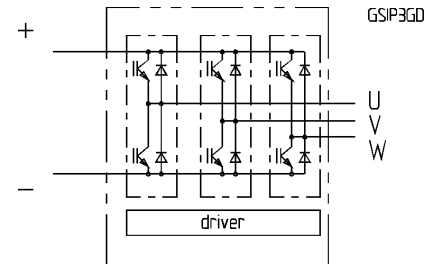
Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
IGBT ¹¹⁾					
V _{(BR)CES}	Driver without supply	≥V _{CES}	—	—	V
I _{CES}	V _{GE} = 0, T _j = 25 °C	—	—	0,4	mA
	V _{CE} = V _{CES} T _j = 125 °C	—	15	—	mA
V _{TO}	T _j = 125 °C	—	—	1,38	V
r _T	T _j = 125 °C	—	—	7,4	mΩ
V _{Cesat}	I _C = 250A, T _j = 125 °C	—	—	3,2	V
V _{Cesat}	I _C = 250A, T _j = 25 °C	—	—	3,05	V
E _{on} + E _{off}	V _{CC} =600/900V, I _C =300A T _j = 125 °C	—	—	90/146	mJ
C _{CHC}	per SkiIP, AC side	—	1,4	—	nF
L _{CE}	Top, Bottom	—	15	—	nH
Inverse Diode ²⁾					
V _F = V _{EC}	I _F = 250A; T _j = 125 °C	—	—	2,43	V
V _F = V _{EC}	I _F = 250A; T _j = 25 °C	—	—	2,55	V
E _{on} + E _{off}	I _F = 300A; T _j = 125 °C	—	—	12	mJ
V _{TO}	T _j = 125 °C	—	0,91	—	V
r _T	T _j = 125 °C	—	3,8	—	mΩ
Thermal Characteristics ¹⁰⁾					
R _{thjs}	per IGBT	—	—	0,090	°C/W
R _{thjs}	per Diode	—	—	0,250	°C/W
R _{thsa} ^{6,10)}	P16 heatsink; see case S3	—	—	0,036	°C/W
Driver					
I _{S1}	Supply current 15V-supply	340+520*f _s /f _{smax} +3,5*I _{AC} /A			mA
I _{S2}	Supply current 24V-supply	250+380*f _s /f _{smax} +2,6*I _{AC} /A			mA
t _{interlock-driver}	Interlock-time	2,3			µs
SKiiPPACK protection					
I _{TRIPSC}	Short circuit protection	375 ± 2%			A
I _{TRIPLG}	Ground fault protection	87 +/- 2%			A
T _{TRIP}	Over-temp. protection	115 ± 5%			°C
U _{DCTRIP} ⁹⁾	U _{DC} -protection	920 ± 2%			V
Mechanical Data					
M1	DC terminals, SI Units	4	—	6	Nm
M2	AC terminals, SI Units	8	—	10	Nm

SKiiPPACK®

SK integrated intelligent Power PACK 3-phase bridge SKiiP

342 GD 120 - 314 CTV ^{7,9)}

Preliminary Data
Case S3



Features

- Short circuit protection, due to evaluation of current sensor signals
- Isolated power supply
- Low thermal impedance
- Optimal thermal management with integrated heatsink
- Pressure contact technology with increased power cycling capability, compact design
- Low stray inductance
- High power, small losses
- Over-temperature protection

- ¹⁾ $T_{heatsink} = 25$ °C, unless otherwise specified
- ²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast)
- ³⁾ without driver
- ⁴⁾ Driver input to DC link/ AC output to heatsink
- ⁵⁾ with Semikron-DC link (low inductance)
- ⁶⁾ other heatsinks on request
- ⁷⁾ C - Integrated current sensors
- ⁸⁾ T - Temperature protection
- ⁹⁾ V - 15 V or 24 V power supply options available for driver:
U - DC link voltage sense
F – Fiber optic connector
- ¹⁰⁾ “s” referenced to temperature sensor
- ¹¹⁾ NPT-technology with homogenous current-distribution